



OPEN

Author Correction: Unveiling the effect of strain engineering on the electrochemical properties of hydrothermally grown nanostructured indium doped ZnSeO₃ for photoanode applications

M. W. Maswanganye, G. L. Kabongo, L. E. Mathevula, B. M. Mothudi & M. S. Dhlamini

Correction to: *Scientific Reports*

<https://doi.org/10.1038/s41598-023-47436-7>, published online 16 November 2023

The original version of this Article omitted an affiliation for M. W. Maswanganye. The correct affiliations are listed below.

Department of Physics, University of South Africa, Florida Park, Roodepoort 1709, Republic of South Africa.

Department of Physics, University of Limpopo, Private Bag X1106, Sovenga, 0727, South Africa.

The original Article has been corrected.



Open Access This article is licensed under a Creative Commons Attribution 4.0 International License, which permits use, sharing, adaptation, distribution and reproduction in any medium or format, as long as you give appropriate credit to the original author(s) and the source, provide a link to the Creative Commons licence, and indicate if changes were made. The images or other third party material in this article are included in the article's Creative Commons licence, unless indicated otherwise in a credit line to the material. If material is not included in the article's Creative Commons licence and your intended use is not permitted by statutory regulation or exceeds the permitted use, you will need to obtain permission directly from the copyright holder. To view a copy of this licence, visit <http://creativecommons.org/licenses/by/4.0/>.

© The Author(s) 2024